

Improved Quad CMOS Analog Switches

FEATURES

- $\pm 22\text{-V}$ Supply Voltage Rating
- TTL and CMOS Compatible Logic
- Low On-Resistance— $r_{DS(on)}$: 45 Ω
- Low Leakage— $I_{D(on)}$: 20 pA
- Single Supply Operation Possible
- Extended Temperature Range
- Fast Switching— t_{ON} : 120 ns
- Low Glitching— Q : 1 pC

BENEFITS

- Wide Analog Signal Range
- Simple Logic Interface
- Higher Accuracy
- Minimum Transients
- Reduced Power Consumption
- Superior to DG201A/202
- Space Savings (TSSOP)

APPLICATIONS

- Industrial Instrumentation
- Test Equipment
- Communications Systems
- Disk Drives
- Computer Peripherals
- Portable Instruments
- Sample-and-Hold Circuits

DESCRIPTION

The DG201B/202B analog switches are highly improved versions of the industry-standard DG201A/202. These devices are fabricated in Vishay Siliconix' proprietary silicon gate CMOS process, resulting in lower on-resistance, lower leakage, higher speed, and lower power consumption.

These quad single-pole single-throw switches are designed for a wide variety of applications in telecommunications, instrumentation, process control, computer peripherals, etc. An improved charge injection compensation design minimizes switching transients. The DG201B and DG202B can handle

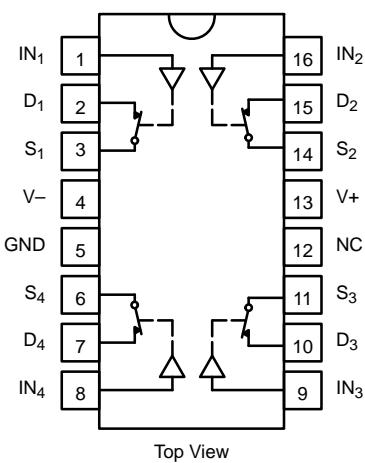
up to $\pm 22\text{-V}$ input signals, and have an improved continuous current rating of 30 mA. An epitaxial layer prevents latchup.

All devices feature true bi-directional performance in the on condition, and will block signals to the supply voltages in the off condition.

The DG201B is a normally closed switch and the DG202B is a normally open switch. (See Truth Table.)

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION

DG201B
Dual-In-Line, SOIC and TSSOP



TRUTH TABLE		
Logic	DG201B	DG202B
0	ON	OFF
1	OFF	ON

Logic "0" $\leq 0.8\text{ V}$
Logic "1" $\geq 2.4\text{ V}$

DG201B/202B

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ORDERING INFORMATION		
Temp Range	Package	Part Number
-40 to 85°C	16-Pin Plastic DIP	DG201BDJ DG202BDJ
	16-Pin CerDIP	DG201BDK DG202BDK
	16-Pin Narrow SOIC	DG201BDY DG202BDY
	16-Pin TSSOP	DG201BDQ DG202BDQ
	16-Pin CerDIP	DG201BAK DG201BAK/883
		DG202BAK DG202BAK/883

ABSOLUTE MAXIMUM RATINGS

Voltages Referenced to V-

V+	44 V
GND	25 V
Digital Inputs ^a V _S , V _D	(V-) -2 V to (V+) +2 V or 30 mA, whichever occurs first
Current, Any Terminal	30 mA
Peak Current, S or D (Pulsed at 1 ms, 10% duty cycle max)	100 mA
Storage Temperature (AK, DK Suffix)	-65 to 150°C
Storage Temperature (DJ, DY, DQ Suffix)	-65 to 125°C

Power Dissipation (Package)^b

16-Pin Plastic DIP ^c	470 mW
16-Pin Narrow SOIC and TSSOP ^d	640 mW
16-Pin CerDIP ^e	900 mW

Notes:

- a. Signals on S_X, D_X, or IN_X exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC Board.
- c. Derate 6.5 mW/°C above 75°C
- d. Derate 7.6 mW/°C above 75°C
- e. Derate 12 mW/°C above 75°C

SCHEMATIC DIAGRAM (TYPICAL CHANNEL)

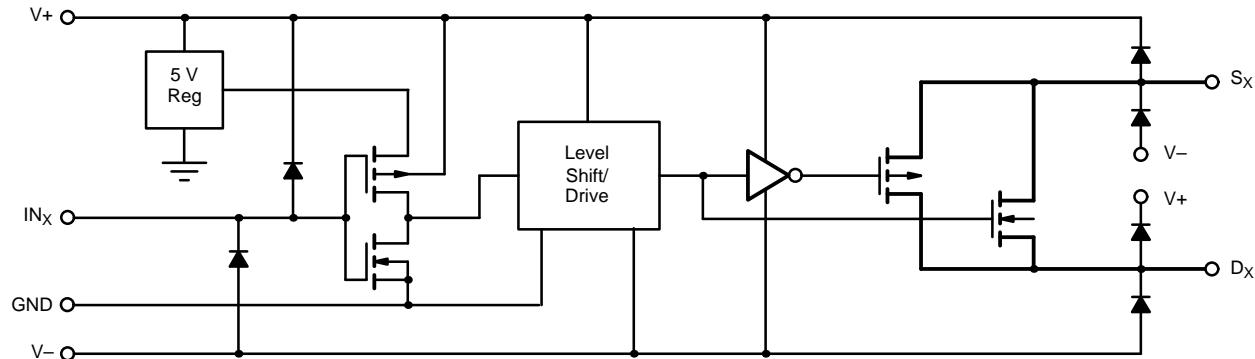


FIGURE 1.

SPECIFICATIONS^a

Parameter	Symbol	Test Conditions Unless Specified $V_+ = 15 \text{ V}$, $V_- = -15 \text{ V}$ $V_{IN} = 2.4 \text{ V}$, 0.8 V^f	Temp ^b	Typ ^c	A Suffix -55 to 125°C		D Suffix -40 to 85°C		Unit
					Min ^d	Max ^d	Min ^d	Max ^d	
Analog Switch									
Analog Signal Range ^e	V_{ANALOG}		Full		-15	15	-15	15	V
Drain-Source On-Resistance	$r_{DS(on)}$	$V_D = \pm 10 \text{ V}$, $I_S = 1 \text{ mA}$	Room Full	45		85 100		85 100	Ω
$r_{DS(on)}$ Match	$\Delta r_{DS(on)}$		Room	2					
Source Off Leakage Current	$I_{S(off)}$	$V_S = \pm 14 \text{ V}$, $V_D = \mp 14 \text{ V}$	Room Full	± 0.01	-0.5 -20	0.5 20	-0.5 -5	0.5 5	nA
Drain Off Leakage Current	$I_{D(off)}$	$V_D = \pm 14 \text{ V}$, $V_S = \mp 14 \text{ V}$	Room Full	± 0.01	-0.5 -20	0.5 20	-0.5 -5	0.5 5	
Drain On Leakage Current	$I_{D(on)}$	$V_S = V_D = \pm 14 \text{ V}$	Room Full	± 0.02	-0.5 -40	0.5 40	-0.5 -10	0.5 10	
Digital Control									
Input Voltage High	V_{INH}		Full		2.4		2.4		V
Input Voltage Low	V_{INL}		Full			0.8		0.8	
Input Current	I_{INH} or I_{INL}	V_{INH} or V_{INL}	Full		-1	1	-1	1	μA
Input Capacitance	C_{IN}		Room	5					pF
Dynamic Characteristics									
Turn-On Time	t_{ON}	$V_S = 2 \text{ V}$ See Switching Time Test Circuit	Room Full	120		300		300	ns
Turn-Off Time	t_{OFF}		Room Full	65		200		200	
Charge Injection	Q	$C_L = 1000 \text{ pF}$, $V_g = 0 \text{ V}$ $R_g = 0 \Omega$	Room	1					pC
Source-Off Capacitance	$C_{S(off)}$	$V_S = 0 \text{ V}$, $f = 1 \text{ MHz}$	Room	5					pF
Drain-Off Capacitance	$C_{D(off)}$		Room	5					
Channel On Capacitance	$C_{D(on)}$	$V_D = V_S = 0 \text{ V}$, $f = 1 \text{ MHz}$	Room	16					
Off Isolation	OIRR	$C_L = 15 \text{ pF}$, $R_L = 50 \Omega$ $V_S = 1 \text{ V}_{\text{RMS}}$, $f = 100 \text{ kHz}$	Room	90					dB
Channel-to-Channel Crosstalk	X_{TALK}		Room	95					
Power Supply									
Positive Supply Current	I_+	$V_{IN} = 0$ or 5 V	Room Full			50 100		50 100	μA
Negative Supply Current	I_-		Room Full		-1 -5		-1 -5		
Power Supply Range for Continuous Operation	V_{OP}		Full		± 4.5	± 22	± 4.5	± 22	V

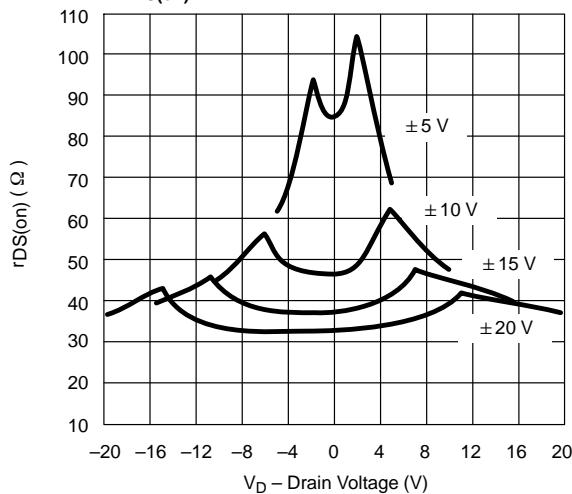
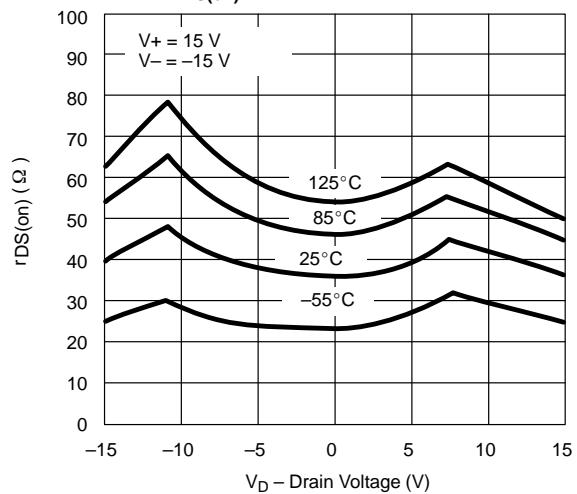
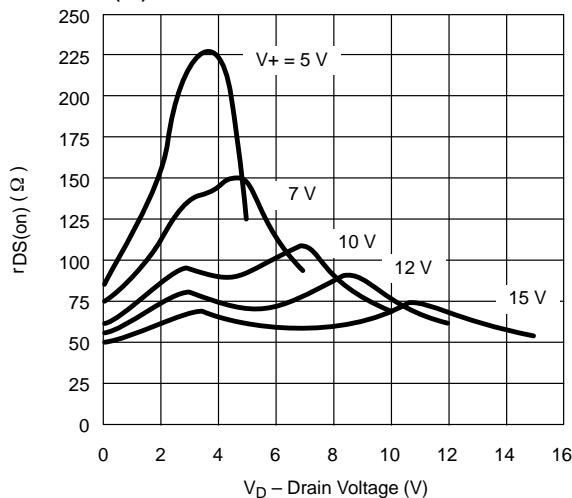
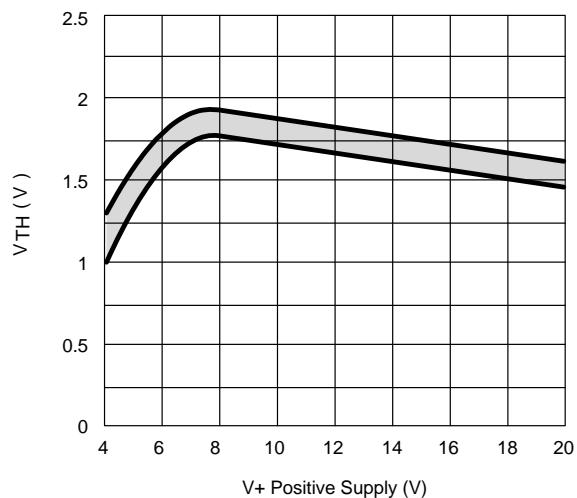
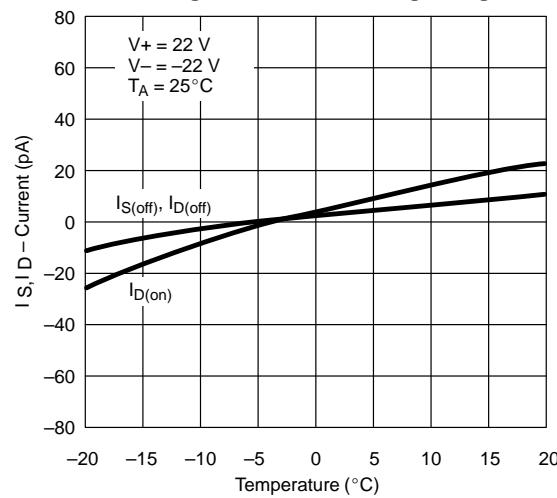
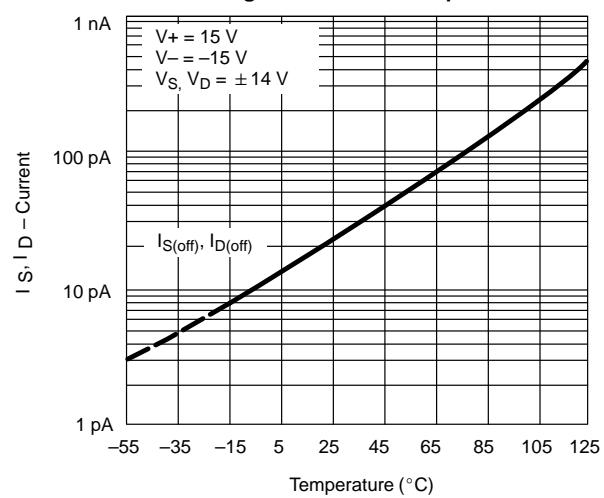
DG201B/202B

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SPECIFICATIONS FOR SINGLE SUPPLY ^a									
Parameter	Symbol	Test Conditions Unless Specified $V_+ = 12 \text{ V}$, $V_- = 0 \text{ V}$ $V_{IN} = 2.4 \text{ V}$, 0.8 Vf	Temp ^b	Typ ^c	A Suffix -55 to 125°C		D Suffix -40 to 85°C		Unit
					Min ^d	Max ^d	Min ^d	Max ^d	
Analog Switch									
Analog Signal Range ^e	V_{ANALOG}		Full		0	12	0	12	V
Drain-Source On-Resistance	$r_{DS(on)}$	$V_D = 3 \text{ V}$, 8 V , $I_S = 1 \text{ mA}$	Room Full	90		160 200		160 200	Ω
Dynamic Characteristics									
Turn-On Time	t_{ON}	$V_S = 8 \text{ V}$ See Switching Time Test Circuit	Room	120		300		300	ns
Turn-Off Time	t_{OFF}		Room	60		200		200	
Charge Injection	Q	$C_L = 1 \text{ nF}$, $V_{gen} = 6 \text{ V}$, $R_{gen} = 0 \Omega$	Room	4					pC
Power Supply									
Positive Supply Current	I_+	$V_{IN} = 0 \text{ or } 5 \text{ V}$	Room Full			50 100		50 100	μA
Negative Supply Current	I_-		Room Full		-1 -5		-1 -5		
Power Supply Range for Continuous Operation	V_{OP}		Full		+4.5	+25	+4.5	+25	V

Notes:

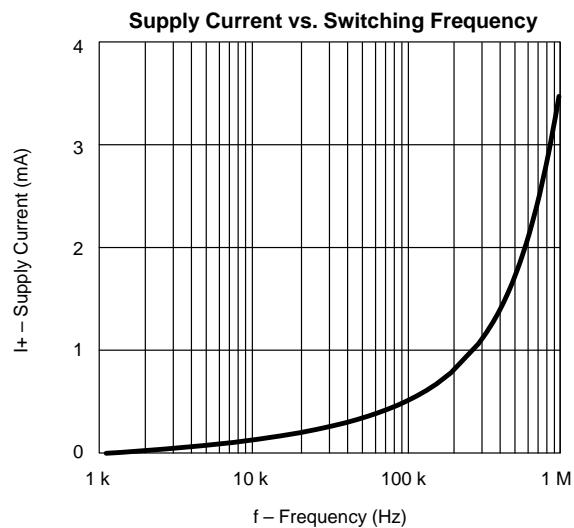
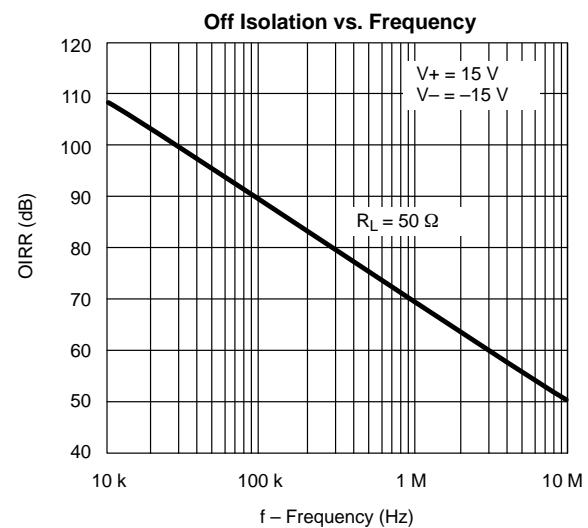
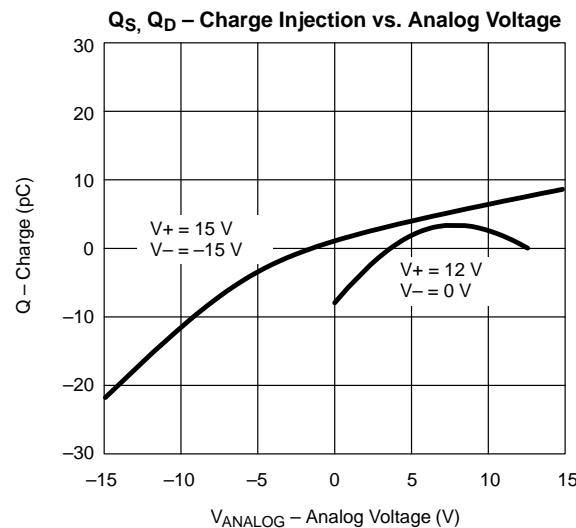
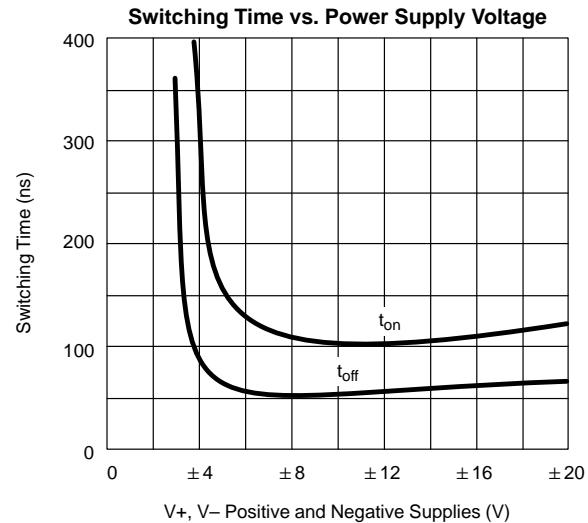
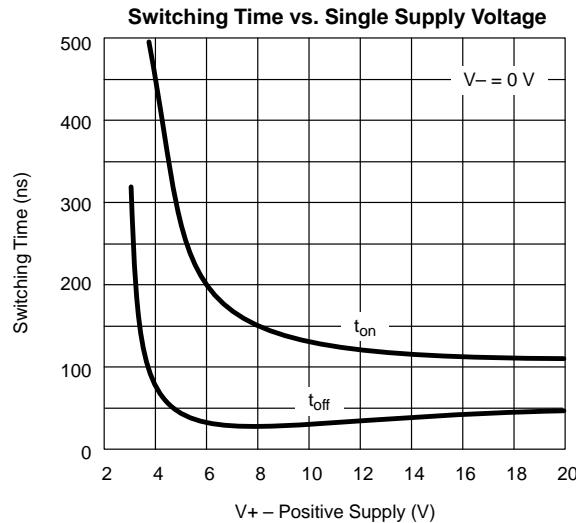
- a. Refer to PROCESS OPTION FLOWCHART.
- b. Room = 25°C, Full = as determined by the operating temperature suffix.
- c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- e. Guaranteed by design, not subject to production test.
- f. V_{IN} = input voltage to perform proper function.

TYPICAL CHARACTERISTICS (25°C UNLESS NOTED) **$r_{DS(on)}$ vs. V_D and Power Supply Voltages** **$r_{DS(on)}$ vs. V_D and Temperature** **$r_{DS(on)}$ vs. V_D and Single Power Supply Voltages****Input Switching Threshold vs. Supply Voltage****Leakage Currents vs. Analog Voltage****Leakage Currents vs. Temperature**

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TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)



TEST CIRCUITS

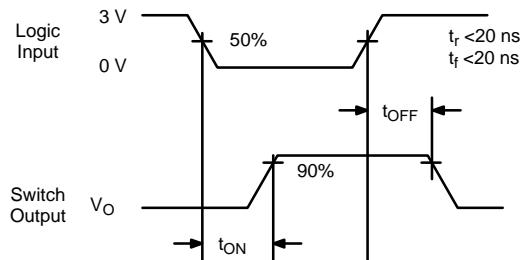
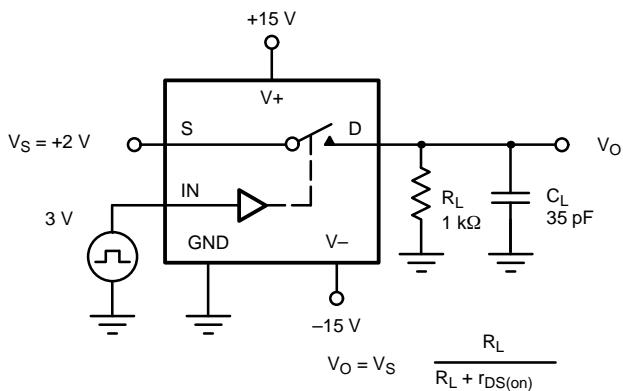


FIGURE 2. Switching Time

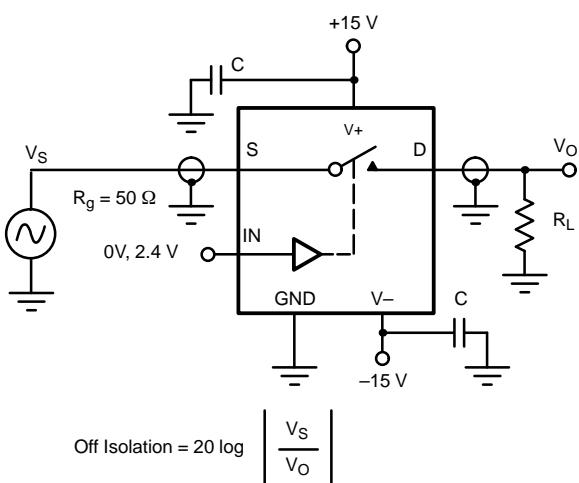


FIGURE 3. Off Isolation

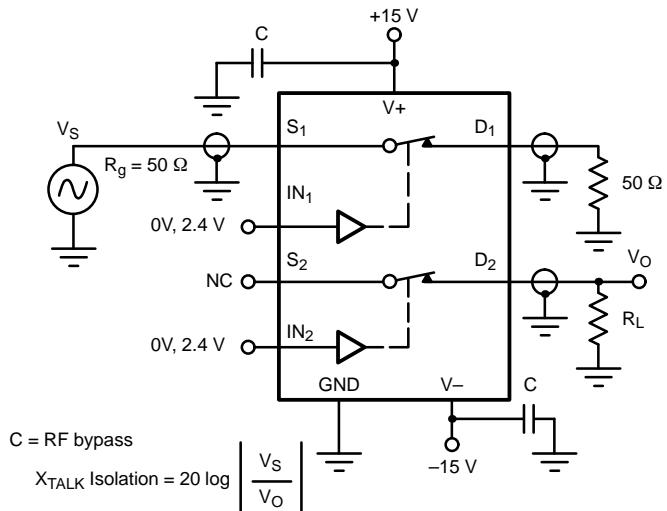
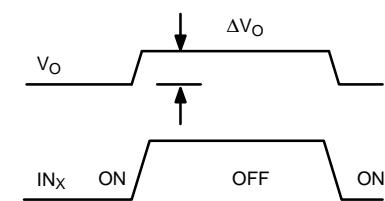
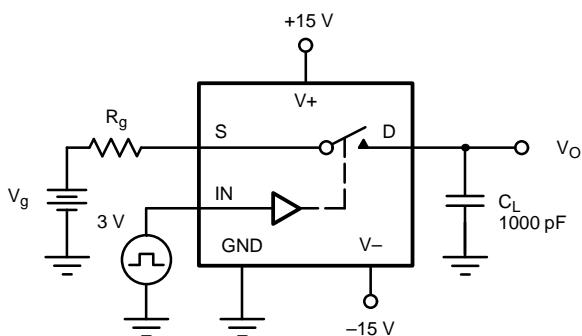


FIGURE 4. Channel-to-Channel Crosstalk



ΔV_O = measured voltage error due to charge injection
 The charge injection in coulombs is $Q = C_L \times \Delta V_O$

FIGURE 5. Charge Injection

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APPLICATIONS

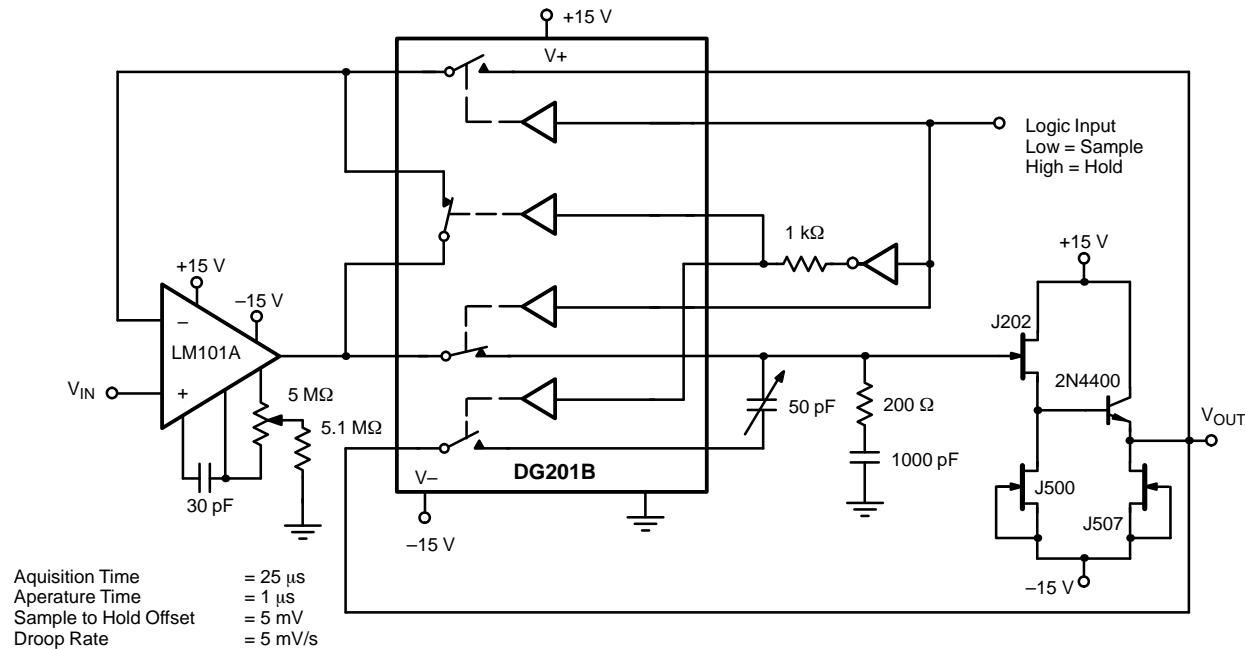


FIGURE 6. Sample-and-Hold

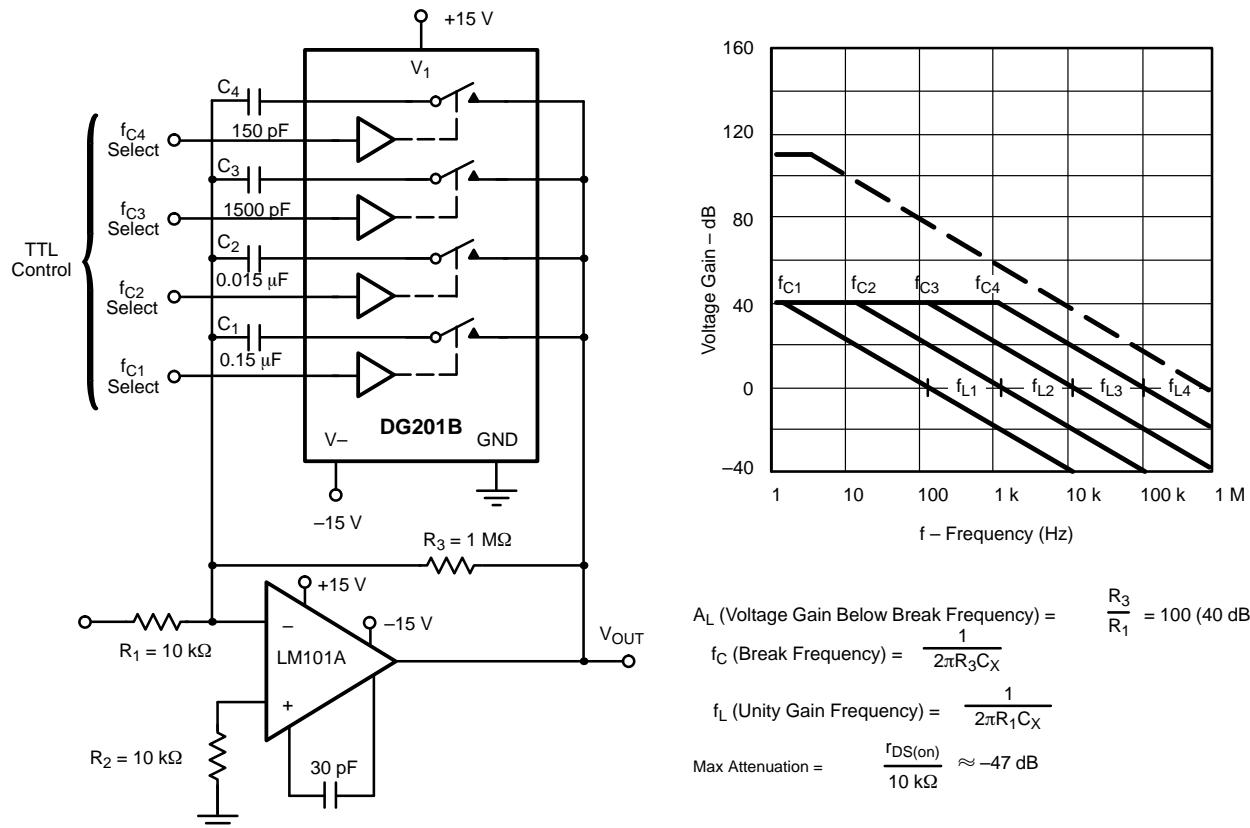
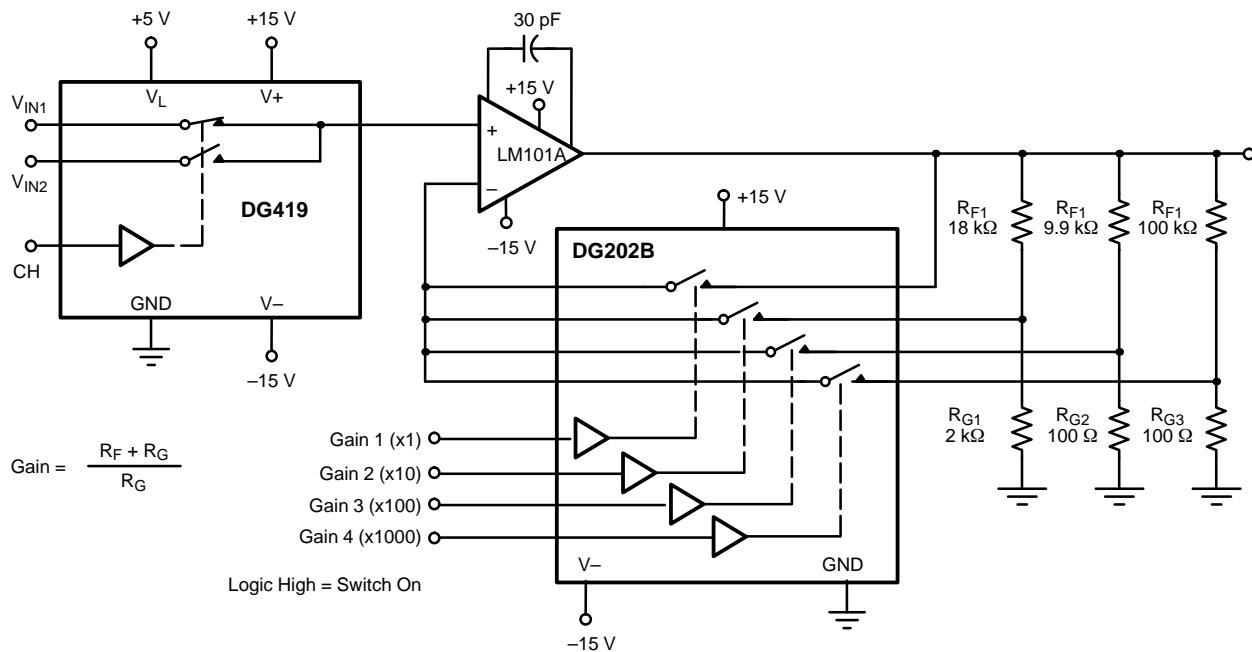


FIGURE 7. Active Low Pass Filter with Digitally Selected Break Frequency

APPLICATIONS**FIGURE 8.** A Precision Amplifier with Digitally Programmable Input and Gains